

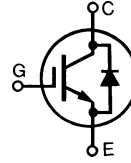
IGBT with Diode ISOPLUS247™ (Electrically Isolated Backside)

Short Circuit SOA Capability

Preliminary data

IXSR 40N60CD1

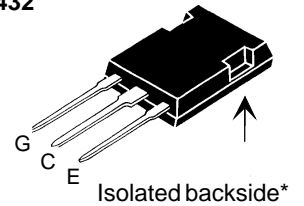
$V_{CES} = 600 \text{ V}$
 $I_{C25} = 62 \text{ A}$
 $V_{CE(SAT)} = 2.5 \text{ V}$
 $t_{fi(typ)} = 70 \text{ ns}$



| Symbol | Test Conditions | Maximum Ratings | |
|---|--|----------------------------------|------------------|
| V_{CES} | $T_J = 25^\circ\text{C}$ to 150°C | 600 | V |
| V_{CGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GE} = 1 \text{ M}\Omega$ | 600 | V |
| V_{GES} | Continuous | ± 20 | V |
| V_{GEM} | Transient | ± 30 | V |
| I_{C25} | $T_C = 25^\circ\text{C}$, limited by leads | 62 | A |
| I_{C90} | $T_C = 90^\circ\text{C}$ | 37 | A |
| I_{CM} | $T_C = 25^\circ\text{C}$, 1 ms | 150 | A |
| SSOA (RBSOA) | $V_{GE} = 15 \text{ V}$, $T_{VJ} = 125^\circ\text{C}$, $R_G = 22 \Omega$ Clamped inductive load, $L = 30 \mu\text{H}$ | $I_{CM} = 80$ @ $0.8 V_{CES}$ | A |
| t_{SC} (SCSOA) | $V_{GE} = 15 \text{ V}$, $V_{CE} = 360 \text{ V}$, $T_J = 125^\circ\text{C}$ $R_G = 22 \Omega$, non repetitive | 10 | μs |
| P_C | $T_C = 25^\circ\text{C}$ | 210 | W |
| T_J | | -55 ... +150 | $^\circ\text{C}$ |
| T_{JM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ |
| V_{ISOL} | 50/60 Hz, RMS $t = 1 \text{ min}$ | 2500 | V~ |
| Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s | | 300 | $^\circ\text{C}$ |
| Weight | PLUS247 | 5 | g |

ISOPLUS 247™ (IXSR)

E 153432



G = Gate, C = Collector,
E = Emitter

* Patent pending

Features

- DCB Isolated mounting tab
- Meets TO-247AD package Outline
- High current handling capability
- Latest generation HDMOS™ process
- MOS Gate turn-on - drive simplicity

Applications

- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies
- AC motor speed control
- DC servo and robot drives
- DC choppers

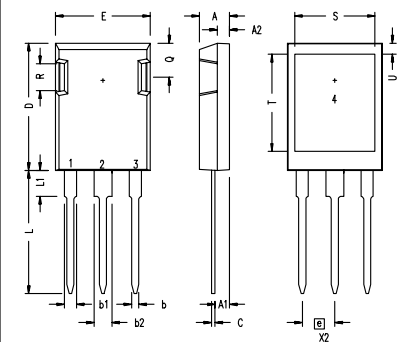
Advantages

- Easy assembly
- High power density
- Very fast switching speeds for high frequency applications

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|---------------|---|---|------|---------------------------|
| | | min. | typ. | max. |
| BV_{CES} | $I_C = 1 \text{ mA}$, $V_{GE} = 0 \text{ V}$ | 600 | | V |
| $V_{GE(th)}$ | $I_C = 4 \text{ mA}$, $V_{CE} = V_{GE}$ | 4 | | V |
| I_{CES} | $V_{CE} = 0.8 \cdot V_{CES}$ $V_{GE} = 0 \text{ V}$ $T_J = 150^\circ\text{C}$ | | | 650 μA 5 mA |
| I_{GES} | $V_{CE} = 0 \text{ V}$, $V_{GE} = \pm 20 \text{ V}$ | | | $\pm 100 \text{ nA}$ |
| $V_{CE(sat)}$ | $I_C = I_T$, $V_{GE} = 15 \text{ V}$ | | | 2.5 V |

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|--------------|--|---|------|---------|
| | | min. | typ. | max. |
| g_{fs} | $I_C = I_T; V_{CE} = 10\text{ V}$, Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$ | 16 | 23 | S |
| C_{ies} | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$ | | 3700 | pF |
| C_{oes} | | | 440 | pF |
| C_{res} | | | 60 | pF |
| Q_g | $I_C = I_T, V_{GE} = 15\text{ V}, V_{CE} = 0.5 V_{CES}$ | | 190 | nC |
| Q_{ge} | | | 45 | nC |
| Q_{gc} | | | 88 | nC |
| $t_{d(on)}$ | Inductive load, $T_J = 25^\circ\text{C}$ | | 50 | ns |
| t_{ri} | $I_C = I_T, V_{GE} = 15\text{ V}, L = 100\ \mu\text{H}$, $V_{CE} = 0.8 V_{CES}, R_G = R_{off} = 2.7\ \Omega$ | | 50 | ns |
| $t_{d(off)}$ | | | 70 | 140 ns |
| t_{fi} | Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 \cdot V_{CES}$, higher T_J or increased R_G | | 70 | 120 ns |
| E_{off} | | | 1.0 | 1.7 mJ |
| $t_{d(on)}$ | Inductive load, $T_J = 125^\circ\text{C}$ | | 50 | ns |
| t_{ri} | $I_C = I_T, V_{GE} = 15\text{ V}, L = 100\ \mu\text{H}$ | | 50 | ns |
| E_{on} | | | 2.2 | mJ |
| $t_{d(off)}$ | Remarks: Switching times may increase for V_{CE} (Clamp) $> 0.8 \cdot V_{CES}$, higher T_J or increased R_G | | 140 | ns |
| t_{fi} | | | 140 | ns |
| E_{off} | | | 1.7 | mJ |
| R_{thJC} | | | | 0.6 K/W |
| R_{thCK} | | 0.15 | | K/W |

ISOPLUS 247 (IXSR) OUTLINE



1 Gate, 2 Drain (Collector)
3 Source (Emitter)
4 no connection

| Dim. | Millimeter | | Inches | |
|----------------|------------|-------|----------|------|
| | Min. | Max. | Min. | Max. |
| A | 4.83 | 5.21 | .190 | .205 |
| A ₁ | 2.29 | 2.54 | .090 | .100 |
| A ₂ | 1.91 | 2.16 | .075 | .085 |
| b | 1.14 | 1.40 | .045 | .055 |
| b ₁ | 1.91 | 2.13 | .075 | .084 |
| b ₂ | 2.92 | 3.12 | .115 | .123 |
| C | 0.61 | 0.80 | .024 | .031 |
| D | 20.80 | 21.34 | .819 | .840 |
| E | 15.75 | 16.13 | .620 | .635 |
| e | 5.45 BSC | | .215 BSC | |
| L | 19.81 | 20.32 | .780 | .800 |
| L ₁ | 3.81 | 4.32 | .150 | .170 |
| Q | 5.59 | 6.20 | .220 | .244 |
| R | 4.32 | 4.83 | .170 | .190 |
| S | 13.21 | 13.72 | .520 | .540 |
| T | 15.75 | 16.26 | .620 | .640 |
| U | 1.65 | 3.03 | .065 | .080 |

Reverse Diode (FRED)

Characteristic Values
($T_J = 25^\circ\text{C}$, unless otherwise specified)

| Symbol | Test Conditions | min. | typ. | max. |
|------------|--|--|------|----------|
| V_F | $I_F = I_T, V_{GE} = 0\text{ V}$, Pulse test $\leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$ | | | 1.8 V |
| I_{RM} | $I_F = I_T, V_{GE} = 0\text{ V}, -di_F/dt = 100\text{ A}/\mu\text{s}$ $V_R = 100\text{ V}$ | | 2 | 2.5 A |
| t_{rr} | | $I_F = 1\text{ A}; -di/dt = 200\text{ A}/\mu\text{s}; V_R = 30\text{ V}$ | | 35 |
| R_{thJC} | | | | 1.15 K/W |

Note: 1. $I_T = 40\text{ A}$